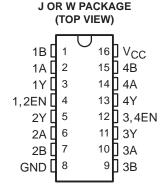
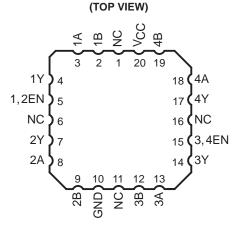
- Meets EIA Standards RS-422-A, RS-423-A, RS-485, and CCITT V.11
- Designed to Operate With Pulse Durations as Short as 20 ns
- Designed for Multipoint Transmission on Long Bus Lines in Noisy Environments
- Input Sensitivity . . . ±200 mV
- Low-Power Consumption . . . 20 mA Max
- Open-Circuit Fail-Safe Design
- Common-Mode Input Voltage Range of –7 V to 12 V

description

The SN55LBC175 is a monolithic quadruple differential line receiver with 3-state outputs and is designed to meet the requirements of the EIA Standards RS-422-A, RS-423-A, RS-485, and CCITT V.11. This device is optimized for balanced multipoint bus transmission at data rates up to and exceeding 10 million bits per second. The receivers are enabled in pairs with an active-high enable input. Each differential receiver input features high impedance, hysteresis for increased noise immunity, and sensitivity of ±200 mV over a common-mode input voltage range of 12 V to -7 V. Fail-safe design ensures that if the inputs are open-circuited, the outputs are always high. This device is designed using the Texas Instruments proprietary LinBiCMOS™ technology allowing low power consumption, high switching speeds, and robustness.



FK PACKAGE



NC - No internal connection

This device offers optimum performance when used with the SN55LBC174 quadruple line driver. The SN55LBC175 is available in the 16-pin CDIP (J) package, a 16-pin CPAK (W) package, or a 20-pin LCCC (FK) package.

The SN55LBC175 is characterized over the military temperature range of -55°C to 125°C.

FUNCTION TABLE (each receiver)

DIFFERENTIAL INP	ENABLE	OUTPUT Y
V _{ID} ≥ 0.2 V	Н	Н
$-0.2 \text{ V} < \text{V}_{\text{ID}} < 0.2 $	2 V H	?
$V_{ID} \le -0.2 V$	Н	L
X	L	Z
Open circuit	Н	Н

H = high level, L = low level, X = irrelevant, Z = high impedance (off), ? = indeterminate



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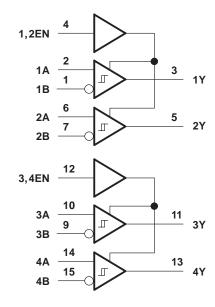


logic symbol†

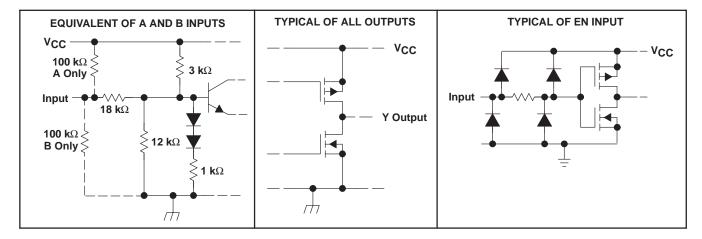
1,2EN ΕN _ D 3 1A 1Y 1B 6 2A 2Y 2B 3,4EN ΕN 10 ⅎ 11 3A 3Y 9 3B 14 4A 13 15 4B

Pin numbers shown are for the J or W package.

logic diagram (positive logic)



schematics of inputs and outputs



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

SN55LBC175 QUADRUPLE LOW-POWER DIFFERENTIAL LINE RECEIVER

SGLS083A - MARCH 1995 - REVISED JUNE 2000

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC} (see Note 1)	–0.3 V to 7 V
Input voltage, A or B inputs, V _I	±25 V
Differential input voltage, V _{ID} (see Note 2)	±25 V
Data and control voltage range	
Continuous total dissipation	See Dissipation Rating Table
Operating free-air temperature range, T _A	–55°C to 125°C
Storage temperature range, T _{Stq}	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

DISSIPATION RATING TABLE

PACKAGE	$T_{\mbox{\scriptsize A}} \leq 25^{\circ}\mbox{\scriptsize C}$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 125°C POWER RATING
FK	1375 mW	11.0 mW/°C	275 mW
J	1375 mW	11.0 mW/°C	275 mW
W	1000 mW	8.0 mW/°C	200 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT	
Supply voltage, V _{CC}		4.75	5	5.25	V
Common-mode input voltage, V _{IC}					
Differential input voltage, V _{ID}	V 18		V		
High-level input voltage, V _{IH}	EN inputs	2			V
Low-level input voltage, V _{IL}	EN inputs			0.8	V
High-level output current, IOH			-8	mA	
Low-level output current, IOL			16	mA	
Operating free-air temperature, TA		-55		125	°C



NOTES: 1. All voltage values are with respect to GND.

^{2.} Differential input voltage is measured at the noninverting input with respect to the corresponding inverting input.

SGLS083A - MARCH 1995 - REVISED JUNE 2000

electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

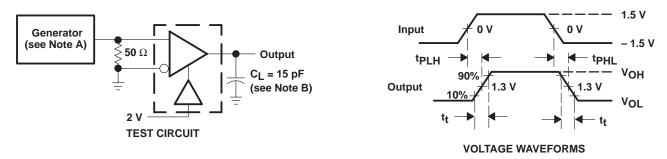
	PARAMETER		TEST CONDITIONS				TYP	MAX	UNIT
V _{IT+}	Positive-going input thresho	ld voltage	$I_O = -8 \text{ mA}$					0.2	V
V _{IT} -	Negative-going input thresh	old voltage	$I_O = 8 \text{ mA}$			-0.2			V
V _{hys}	Hysteresis voltage (V _{IT+} -	V _{IT} _)					45		mV
VIK	Enable input clamp voltage		$I_{I} = -18 \text{ mA}$				-0.9	-1.5	V
Vон	High-level output voltage		V _{ID} = 200 mV,	I _{OH} = -8 m/	4	3.5	4.5		V
\/	Low lovel output voltage	$V_{ID} = -200 \text{ mV},$	$I_{OL} = 8 \text{ mA}$			0.3	0.5	V	
VOL	Low-level output voltage		$V_{ID} = -200 \text{ mV},$	$I_{OL} = 8 \text{ mA},$	T _A = 125°C			0.7	V
loz	High-impedance-state output	VO = 0 V to VCC					±20	μΑ	
			V _{IH} = 12 V,	$V_{CC} = 5 V$,	Other inputs at 0 V	0.7	1		
l	Bus input current	A or B inputs	V _{IH} = 12 V,	$V_{CC} = 0 V$,	Other inputs at 0 V		0.8	1	mA
'1			$V_{IH} = -7 V$,	$V_{CC} = 5 V$,	Other inputs at 0 V		-0.5	-0.8	IIIA
			$V_{IH} = -7 V$,	$V_{CC} = 0 V$,	Other inputs at 0 V		-0.4	-0.8	
lн	High-level enable input curr	ent	V _{IH} = 5 V					±20	μΑ
I _{IL}	Low-level enable input curre	V _{IL} = 0 V					-20	μΑ	
los	Short-circuit output current		V _O = 0			·	-80	-120	mA
loo	Supply current	_	Outputs enabled,	$I_{O} = 0$,	V _{ID} = 5 V		11	20	mA
Icc	очрріў сипепі		Outputs disabled				0.9	0.7 1 0.8 1 -0.5 -0.8 -0.4 -0.8 ±20 -20 -80 -120 11 20	IIIA

 $[\]dagger$ All typical values are at V_{CC} = 5 V and T_A = 25°C.

switching characteristics, $V_{CC} = 5 \text{ V}$, $C_L = 15 \text{ pF}$

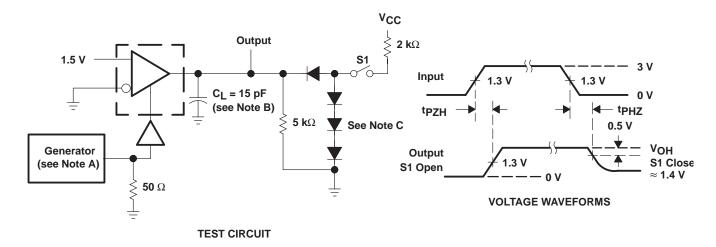
	PARAMETER	TEST CONDITIONS	TA	MIN	TYP	MAX	UNIT	
t	Propagation delay time, high- to low-level output	$V_{ID} = -1.5 \text{ V to } 1.5 \text{ V},$	1.5 V, 25°C 11 22		22	30	ns	
tPHL	Propagation delay time, high- to low-level output	See Figure 1	-55°C to 125°C			35	115	
tour	Propagation delay time, low- to high-level output	$V_{ID} = -1.5 \text{ V to } 1.5 \text{ V},$	25°C	25°C 11 22 30		ns		
^t PLH	1 Topagation delay time, low- to high-level output	See Figure 1	-55°C to 125°C			35	113	
t	Output enable time to high level	See Figure 2	25°C		17	40	ns	
^t PZH	Output enable time to high level	See Figure 2	-55°C to 125°C			45	115	
+	Output enable time to low level	See Figure 3	25°C	18 30	30	ns		
tPZL	Output enable time to low level	See Figure 3	-55°C to 125°C			35	115	
	Output dipable time from high level	See Figure 2	25°C	30 4	40			
tPHZ	Output disable time from high level	See Figure 2	-55°C to 125°C			55	ns	
·	Output disable time from low level	See Figure 3	25°C		23	30	no	
^t PLZ	Output disable time from low level	See Figure 3	-55°C to 125°C			45	ns	
	Dulge elsew (ltm	Coo Figure 4	25°C	25°C 4	6			
tsk(p)	Pulse skew (tpHL - tpLH)	See Figure 1	-55°C to 125°C			7	ns	
+.	Transition time	Soo Figure 1	25°C		3	10	no	
t _t	Hansiion uille	See Figure 1	−55°C to 125°C			16	ns	

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle \leq 50%, $t_{\text{f}} \leq$ 6 ns, $t_{\text{f}} \leq$ 7 ns, $t_{\text{f}} \leq$ 8 ns, $t_{\text{f}} \leq$ 9 ns, t
 - B. C_I includes probe and jig capacitance.

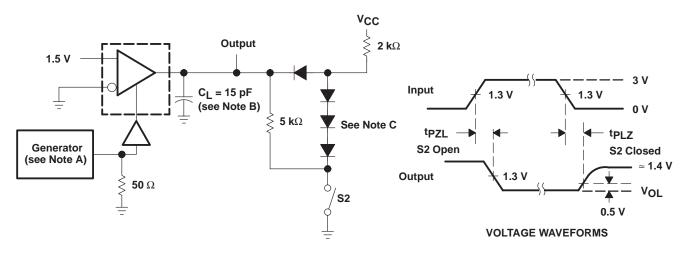
Figure 1. tpLH and tpHL Test Circuit and Voltage Waveforms



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle \leq 50%, $t_f \leq$ 6 ns, $t_f \leq$ 7 ns, $t_f \leq$ 8 ns, $t_f \leq$ 9 ns, $t_$
 - B. C_L includes probe and jig capacitance.
 - C. All diodes are 1N916 or equivalent.

Figure 2. t_{PHZ} and t_{PZH} Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION

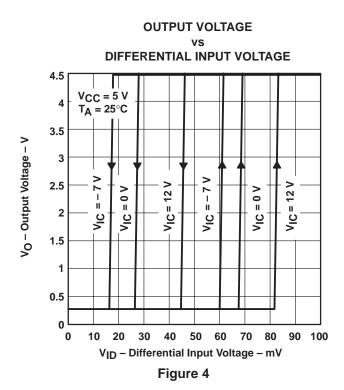


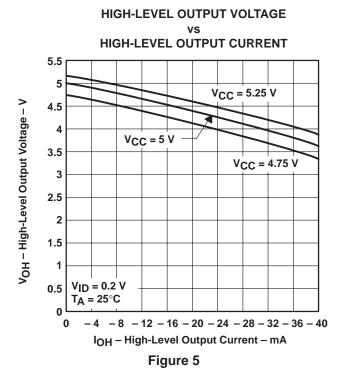
TEST CIRCUIT

- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR = 1 MHz, duty cycle \leq 50%, $t_{\Gamma} \leq$ 6 ns, $t_{f} \leq$ 6 ns, $t_{O} =$ 50 Ω .
 - B. C_L includes probe and jig capacitance.
 - C. All diodes are 1N916 or equivalent.

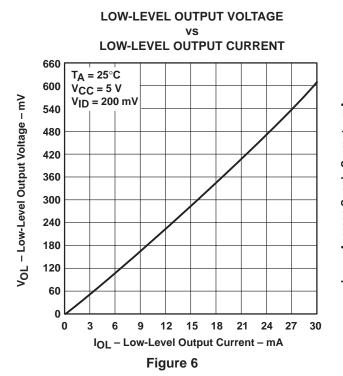
Figure 3. tpzL and tpLZ Test Circuit and Voltage Waveforms

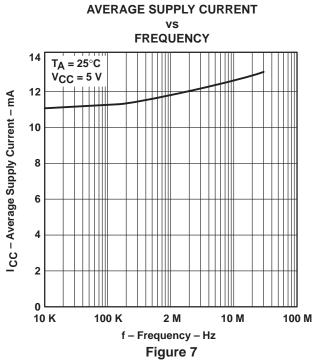
TYPICAL CHARACTERISTICS

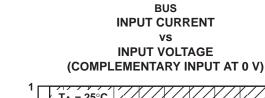


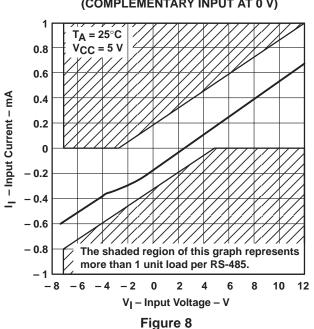


TYPICAL CHARACTERISTICS









24.5 V_{CC} = 5 V C_L = 15 pF V_{IO} = ±1.5 V 23.5 tpHL 22.5 22

20

Figure 9

 T_A – Free-Air Temperature – $^{\circ}$ C

40

60

PROPAGATION DELAY TIME

- 40

- 20

0

100





6-Feb-2020

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9076603Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9076603Q2A SNJ55 LBC175FK	Samples
5962-9076603QEA	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9076603QE A SNJ55LBC175J	Samples
5962-9076603QFA	ACTIVE	CFP	W	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9076603QF A SNJ55LBC175W	Samples
SN55LBC175J	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	SN55LBC175J	Samples
SNJ55LBC175FK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9076603Q2A SNJ55 LBC175FK	Samples
SNJ55LBC175J	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9076603QE A SNJ55LBC175J	Samples
SNJ55LBC175W	ACTIVE	CFP	W	16	1	TBD	Call TI	N / A for Pkg Type	-55 to 125	5962-9076603QF A SNJ55LBC175W	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".



PACKAGE OPTION ADDENDUM

6-Feb-2020

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF SN55LBC175:

Catalog: SN75LBC175

NOTE: Qualified Version Definitions:

Catalog - TI's standard catalog product

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a metal lid.
- D. Falls within JEDEC MS-004



W (R-GDFP-F16)

CERAMIC DUAL FLATPACK



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP2-F16



14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

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